

28.8 dBm Power-LNA™ Tuning Range: 1.5 – 3.8 GHz



Features

Reference: 5V/160mA/1.9GHz

- Gain: 15.0 dB
- OP1dB: 28.8 dBm
- 0IP3: 46.0 dBm
- Eval Board NF:0.9 dB
- Flexible Bias Voltage and Current
- Process: GaAs pHEMT

Applications

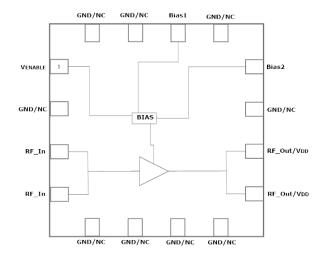
- Power Amplifier
- Linear Driver Amplifier for High PAR
 Waveforms
- Multi-stage LNA

Product Description

GRF5110 is a high linearity PA /Linear Driver with low noise figure (NF). It delivers excellent P1dB, IP3 and NF over a wide range of frequencies with fractional bandwidths of roughly 5 to 10%.

The device can be tuned over a wide range of frequencies from around 1.5 GHz to 3.8 GHz.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device s-parameters.



3.0 x 3.0 mm QFN-16

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Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Drain Voltage	Vdd		6.0	V
Transient Average RF Input Power: (Load VSWR < 2:1; Duration: <1 hour)	P _{IN MAX}		24.0	dBm
Operating Temperature (Package Heat Sink)	T _{AMB}	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P _{DISS MAX}		1.0	W
Electrostatic Discharge:				
Charged Device Model: (TBD)	CDM	1500		V
Human Body Model:	HBM	250		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	-



Caution! ESD Sensitive Device

Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF5110 landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

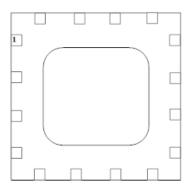
Link to manufacturing note

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Pin Out (Top View)



Pin Assignments:

Pin	Name	Description	Note
1	Venable	Enable Voltage Input	VENABLE and series resistor set IDDQ. VENABLE < =0.2 volts disables device. On-die pull-down resistor will turn the part off if this node is allowed to float.
2	NC	No Connect or Ground	No internal connection to die
3	RF_In	RF Input	Pins 3-4 tied together on system board
4	RF_In	RF Input	Pins 3-4 tied together on system board
5	NC	No Connect or Ground	No internal connection to die
6	NC	No Connect or Ground	No internal connection to die
7	NC	No Connect or Ground	No internal connection to die
8	NC	No Connect or Ground	No internal connection to die
9	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
10	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
11	NC	No Connect or Ground	No internal connection to die
12	Bias2	Bias Circuit Supply	Connect to Vbb through external resistor
13	NC	No Connect or Ground	No internal connection to die
14	Bias1	Bias Circuit Ground	Consult application schematic
15	NC	No Connect or Ground	No internal connection to die
16	NC	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Rec- ommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.





Nominal Operating Parameters:

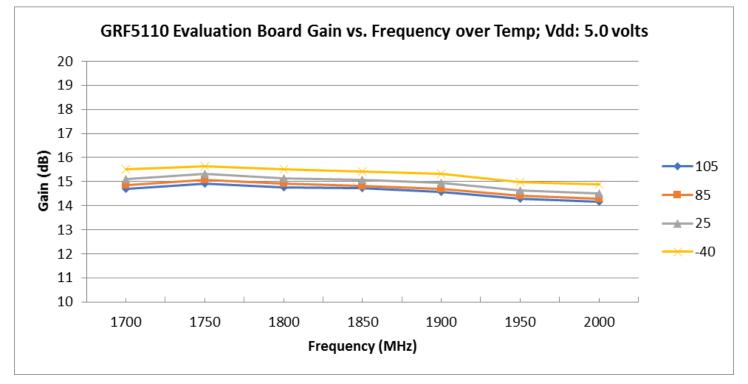
Parameter	Symphol	Specification			Unit	Condition	
Farameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Target Performance (1.7 to 2.2 GHz Tune)						Bias: 5.0 V and 160 mA un- less otherwise noted. (+25C)	
Test Frequency	FTEST		1.9		GHz		
Gain	S(2,1)	14.0	15.0		dB		
Noise Figure (Evaluation Board)	NF		0.9		dB		
Output 1dB Compression Point	OP1dB	27.3	28.8		dBm		
Output Third Order Intercept Point	OIP3		46.0		dBm		
Switching Rise Time	Trise		100		ns		
Switching Fall Time	TFALL	1	800		ns		
Quiescent Supply Current	Iddq		160	190	mA	Vdd=Venable=5.0volts Rbias: 5.5k ohms	
Enable Current	ENABLE		2.0		mA		
Disabled Mode							
Supply Current (Leakage)	I _{DD}		30		uA		
Thermal Data							
Thermal Resistance: (IR Scan Method)	Θјс		80		°C/W		
Channel Temperature @ +85C Refer- ence (package heat sink)	Tchannel		149 (See note)		°C	VDD: 5.0 volts; IDDQ: 160 mA PDISS: 800 mW; No RF	

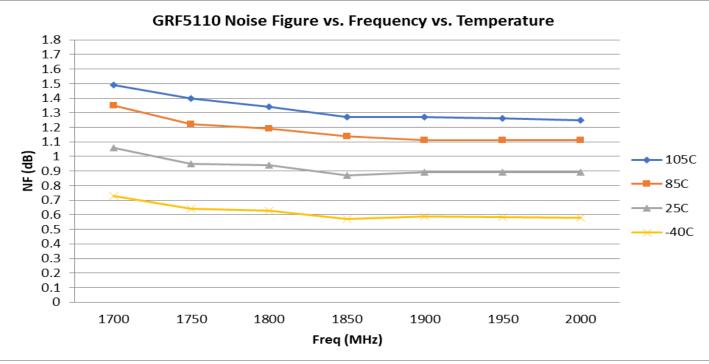
Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.



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GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)



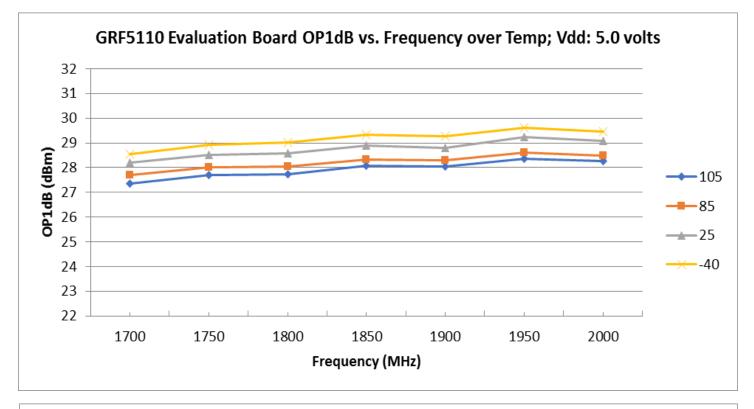


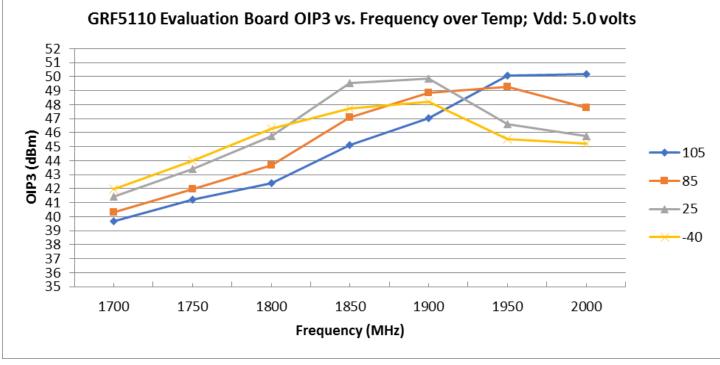
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GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)





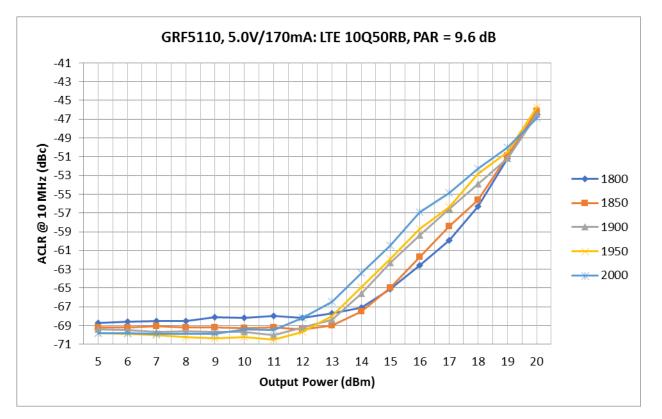
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GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)

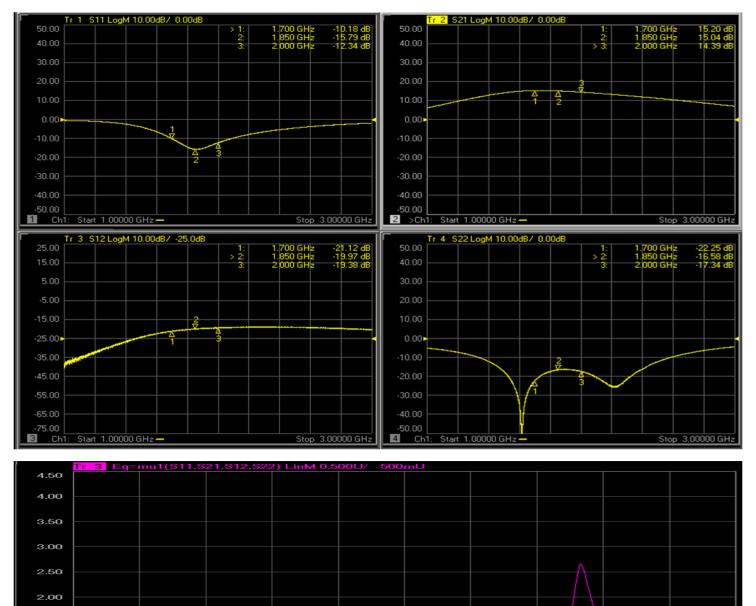


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GRF5110 Evaluation Board S-Pars: (1.7 to 2.0 GHz Tune)



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Ch1

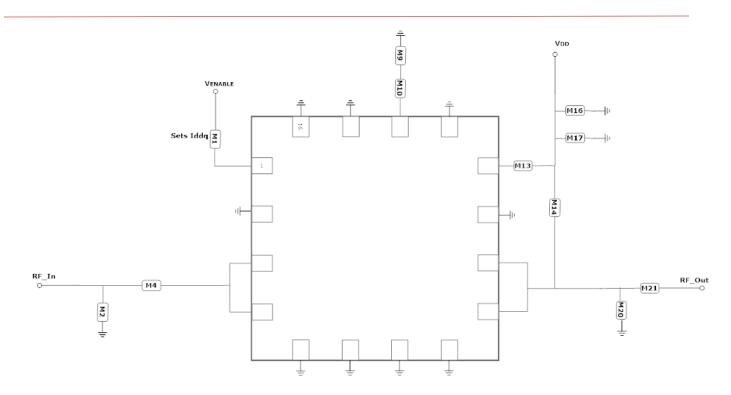
Start 10.0000 MHz

1.50 1.00 0.50 0.00

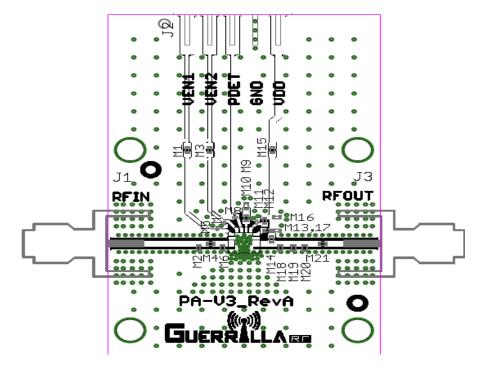
Stop 20.0000 GH



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GRF5110 Application Schematic: (1.7 to 2.0 GHz)



GRF5110 Evaluation Board Assembly Drawing

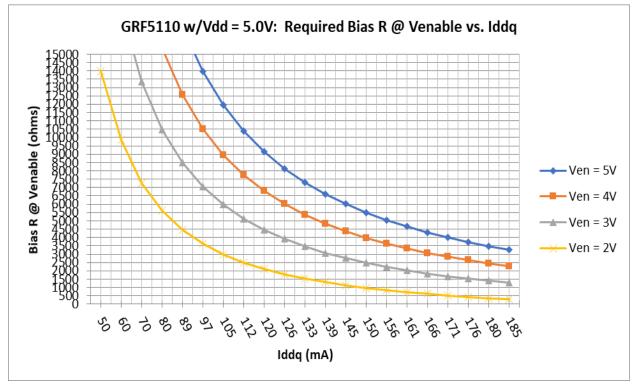
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GRF5110 Evaluation Board BOM: (1.7-2.0 GHz)

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M2	Inductor: High Q	Coilcraft	HP	2.7 nH	0402	ok
M4	Capacitor: High Q	Murata	GJM	2.0 pF	0402	ok
M9	Resistor	Various	5%	0 Ohm	0402	ok
M10	Inductor	Murata	LQP/LQG	12 nH	0402	ok
M13	Resistor	Various	5%	0 Ohm	0402	ok
M14	Inductor: High Q	Coilcraft	HP	18 nH	0402	ok
M16	Capacitor	Murata	GRM	0.1 uF	0402	ok
M17	Capacitor	Murata	GRM	100 pF	0402	ok
M20	Capacitor	Murata	GJM	1.5 pF	0402	ok
M21	Capacitor	Murata	GJM	10 pF	0402	ok

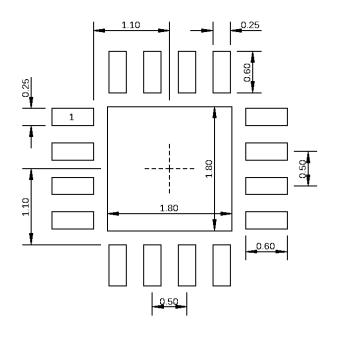


GRF5110 Bias Resistor (M1) Selection Curves

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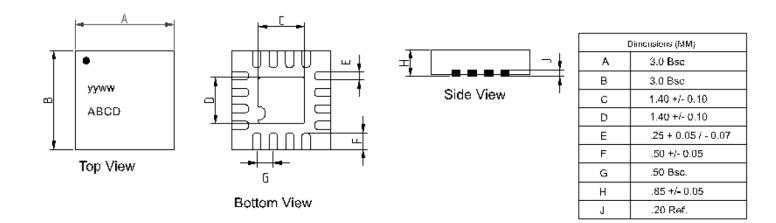
GRF5110





Dimensions in millimeters

3.0 mm QFN-16 Suggested PCB Footprint (Top View)



3.0 mm QFN-16 Package Dimensions

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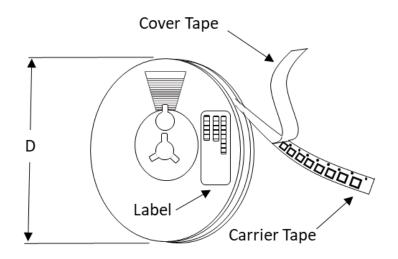




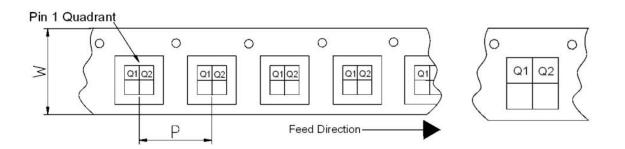
Tape and Reel Information:

Guerrilla RF's Tape and Reel specification complies with the Electronics Industries Association (EIA) standards for 'Embossed Carrier Tape of Surface Mount Components for Automatic Handling". Reference EIA-481. See the table on the following page for Tape and Reel specifications along with units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape, wound into a plastic reel. Each reel will be packaged in a cardboard box. There will be product labels on the reel, the protective ESD bag and the outside surface of the box.



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information

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Tape and Reel Specification and Device Package Information Table

Package			Carrier Tape			Reel		
Туре	Dimensions (mm)	Leads	Weight (mg)	Width (W) (mm)	Pocket Pitch (P) (mm)	Pin 1 Quad- rant	Diameter (D) (inches)	Units per Reel
QFN	2.0 x 2.0 x 0.50	12	7	8	4	Q1	7	2500
QFN	3.0 x 3.0 x 0.85	16	24	12	8	Q1	7	1500
DFN	1.5 x 1.5 x 0.45	6	4	8	4	Q1	7	2500
DFN	2.0 x 2.0 x 0.75	8	12	8	4	Q1	7	2500
LFM	3.5 x 3.5 x 0.75	See	TBD	12	8	Q2	7	1500
LFM	4.0 x 4.0 x 0.75	See note	TBD	12	8	Q2	7	1500

Note: Lead count may vary. Reference applicable product data sheet



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Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on de- vice size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

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